

CMOS VOLTAGE DETECTOR

DESCRIPTION

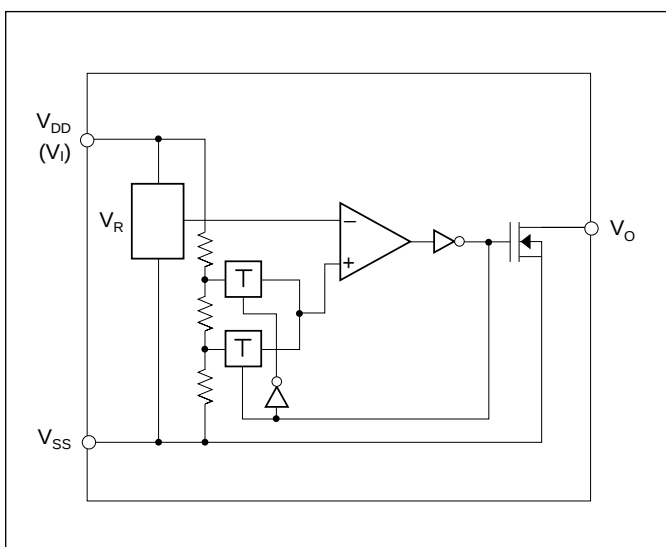
The SCI7700Y Series/SCI7701Y Series are a series of low-power precision voltage detectors, which do not require external adjustments. The SCI7700Y Series/SCI7701Y Series have such applications as battery-life detection, power supply fault monitoring, over/under-voltage protection and battery back-up switching. The SCI7700Y Series is an open-drain Nch output type and the SCI7701Y Series is a CMOS output type. Both are available in SOT 89-3pin (plastic) packages.

FEATURES

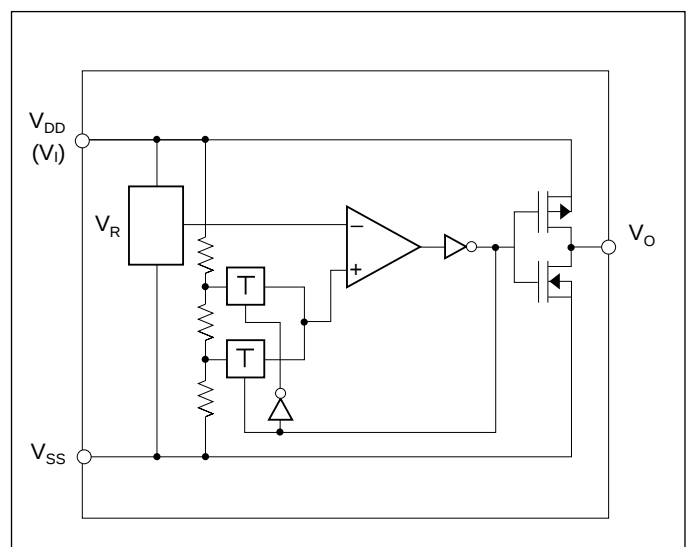
- Many types see the next page
- Low operating supply current Typ 1.8 μ A (SCI7700YNA, $V_{DD}=3.0V$)
- Low range of operating voltage Typ 1.2V (SCI7700YNA)
- Temperature coefficient of detection voltage Typ (detection voltage/reference voltage) $\times 0.1$ (mV/ $^{\circ}$ C)
- Hysteresis difference Typ detection voltage $\times 0.05V$
- Package SOT 89-3pin (plastic)

BLOCK DIAGRAM

SCI7700Y Series



SCI7701Y Series

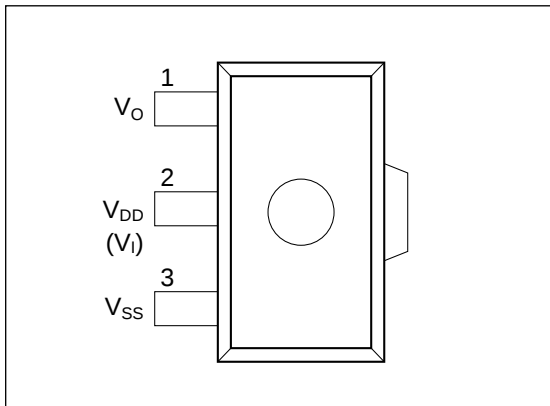


SCI7700/01Y Series

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■ PIN CONFIGURATION



(Ta = 25°C)

Type No.	Output Mode	Detection Voltage (V)			Operating Voltage (V)	Operating Supply Current (μA)
		Min	Typ	Max		
SCI7700YVA	Open drain Nch	0.90	0.95	1.00	0.8 to 5.0	Typ 1.4 (VDD=1.5V)
SCI7700YAA	Open drain Nch	1.00	1.05	1.10	0.9 to 5.0	Typ 1.4 (VDD=1.5V)
SCI7700YAS	Open drain Nch	1.05	1.10	1.15	0.8 to 10.0	Typ 1.4 (VDD=1.5V)
SCI7700YBA	Open drain Nch	1.10	1.15	1.20	0.9 to 5.0	Typ 1.4 (VDD=1.5V)
SCI7700YNA	Open drain Nch	1.85	1.90	1.95	1.2 to 10.0	Typ 1.8 (VDD=3.0)
SCI7700YCA	Open drain Nch	2.10	2.15	2.20	0.9 to 5.0	Typ 1.8 (VDD=3.0V)
SCI7700YFA	Open drain Nch	2.60	2.70	2.80	1.5 to 10.0	Typ 1.8 (VDD=3.0V)
SCI7700YTA	Open drain Nch	3.80	4.00	4.20	1.5 to 10.0	Typ 2.6 (VDD=6.0V)
SCI7701YCA	CMOS	2.10	2.15	2.20	1.5 to 10.0	Typ 1.8 (VDD=3.0V)
SCI7701YCB*						
SCI7701YPA	CMOS	2.20	2.25	2.30	1.5 to 10.0	Typ 1.8 (VDD=3.0V)
SCI7701YSA	CMOS	2.30	2.35	2.40	1.5 to 10.0	Typ 1.8 (VDD=3.0V)
SCI7701YEA	CMOS	2.50	2.55	2.60	1.5 to 10.0	Typ 1.8 (VDD=3.0V)
SCI7701YFA	CMOS	2.60	2.70	2.80	1.5 to 10.0	Typ 1.8 (VDD=3.0V)
SCI7701YFB*						
SCI7701YRA	CMOS	2.70	2.80	2.90	1.5 to 10.0	Typ 1.8 (VDD=3.0V)
SCI7701YGA	CMOS	2.90	3.00	3.10	1.5 to 10.0	Typ 2.2 (VDD=4.5V)
SCI7701YHA	CMOS	3.10	3.20	3.30	1.5 to 10.0	Typ 2.2 (VDD=4.5V)
SCI7701YTA	CMOS	3.80	4.00	4.20	1.5 to 10.0	Typ 2.6 (VDD=6.0V)
SCI7701YMA	CMOS	4.00	4.15	4.30	1.5 to 10.0	Typ 2.6 (VDD=6.0V)
SCI7701YJA	CMOS	4.30	4.45	4.60	1.5 to 10.0	Typ 2.6 (VDD=6.0V)
SCI7701YKA	CMOS	4.60	4.75	4.90	1.5 to 10.0	Typ 2.6 (VDD=6.0V)
SCI7701YLA	CMOS	4.90	5.10	5.30	1.5 to 10.0	Typ 2.6 (VDD=6.0V)

* Reverse output polarity

■ ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Ratings	Unit
Input voltage (supply voltage)	VDD (VI) – VSS	12	V
Output voltage	VO	VDD + 0.3 to VSS – 0.3	V
Output current	IO	50	mA
Power dissipation (TA ≤ 25°C)	PD	400	mW
Operating temperature	Topr	–30 to 85	°C
Storage temperature	Tstg	–65 to 150	°C
Soldering temperature and time	Tsol	260°C, 10s (at lead)	—

Note: Although this IC has electrostatic protection circuit, damage may still occur if very high electrostatic potentials are applied.

Note: When this IC is soldered in the solder-reflow process, be sure to maintain the reflow furnace at the curve shown in “Fig. 3–5 Reflow Furnace Temperature Curve” of DATA BOOK. This IC cannot be exposed to the high temperature of the the solder dipping.

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■ ELECTRICAL CHARACTERISTICS**● SCI7700Y Series/SCI7701Y Series**

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Detection voltage	V _{DET}	Ta=25°C	See page 2			V
Operating supply current	I _{DDO}	V _{DD} =1.5V, Ta=25°C	—	1.4	3.0	μA
		V _{DD} =3.0V, Ta=25°C	—	1.8	4.0	
		V _{DD} =4.5V, Ta=25°C	—	2.2	5.0	
		V _{DD} =6.0V, Ta=25°C	—	2.6	6.0	
Supply (Operating) voltage	V _{DD} (V _I)	Ta=−30 to 85°C	See page 2			V
Hysteresis difference	ΔV _{DET}	Ta=−30 to 85°C	—	V _{DET} ×0.05*	—	V
Temperature coefficient of V _{DET}	V _{DET} (Ta=70°C)-V _{DET} (Ta=−20°C)	Ta=−30 to 85°C	Typ(V _{DET} /V _R)×0.1			mV/°C
	90					

* V_{DET} × 0.04 (Typ) about SCI7700Y_{TA}/SCI7701Y_{TA}/SCI7701Y_{MA}/SCI7701Y_{JA}/SCI7701Y_{KA}/SCI7701Y_{LA}**● SCI7700Y_{VA}/SCI7700Y_{AA}/SCI7700Y_{BA}**

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output current		V _{DD} = 0.85V, V _{DS} = 0.5V, Ta = 25°C	0.05	0.40	1.00	mA
	I _O (Nch)	V _{DD} = 0.95V, V _{DS} = 0.5V, Ta = 25°C	0.15	0.70	1.50	
		V _{DD} = 1.05V, V _{DS} = 0.5V, Ta = 25°C	0.30	1.00	2.00	
Reference voltage supply	V _R	Ta = 25°C	0.70	0.80	0.90	V

V_{DS}: Voltage between drain and source

■ ELECTRICAL CHARACTERISTICS (Cont.)

- **SCI7700YNA/SCI7700YTA/SCI7701YCA/SCI7701YPA/SCI7701YSA/SCI7701YEA/SCI7701YFA/
SCI7701YRA/SCI7701YGA/SCI7701YHA/SCI7701YTA/SCI7701YMA/SCI7701YJA/SCI7701YKA/
SCI7701YLA**

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output current	Io (Nch)	VDD=0.95V, VDS=0.5V, Ta=25°C	0.03	0.15	0.50	mA
		VDD=1.00V, VDS=0.5V, Ta=25°C	0.05	0.22	0.60	
		VDD=1.20V, VDS=0.5V, Ta=25°C	0.30	0.70	1.50	
		VDD=2.40V, VDS=0.5V, Ta=25°C	1.40	2.00	2.30*1	
		VDD=3.60V, VDS=0.5V, Ta=25°C	1.50	2.30	2.60*2	
	Io (Pch)	VDD=4.50V, VDS=2.1V, Ta=25°C	1.7	2.0	2.3	
		VDD=8.00V, VDS=2.1V, Ta=25°C	2.8	3.1	3.8	
Reference voltage supply	VR	Ta=25°C	0.90	1.00	1.10	V

- * 1: 3.30 mA about SCI7700YTA, * 2: 4.00 mA about SCI7700YTA VDS: Voltage between drain and source
 * Please inquire IC sales department about SCI7700YCA.

- **SCI7700YAS/SCI7700YFA/SCI7701YCB/SCI7700YFB**

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output current	Io (Nch)	VDD=0.8V, VOUT=0.1V, Ta=25°C*1	0.01	—	—	mA
		VDD=2.4V, VOUT=0.5V, Ta=25°C*2	1.7	2.5	3.3	
		VDD=2.4V, VOUT=0.5V, Ta=25°C*3	1.4	1.8	2.3	
		VDD=3.0V, VOUT=0.5V, Ta=25°C*4	1.5	2.0	2.5	
	Io (Pch)	VDD=2.0V, VOUT=1.5V, Ta=25°C*3	0.1	0.3	0.9	
		VDD=2.0V, VOUT=1.5V, Ta=25°C*4	0.1	2.0	2.5	
Reference voltage supply	VR	Ta=25°C*1	0.7	0.8	0.9	V
		Ta=25°C*2,*3,*4	0.9	1.0	1.1	

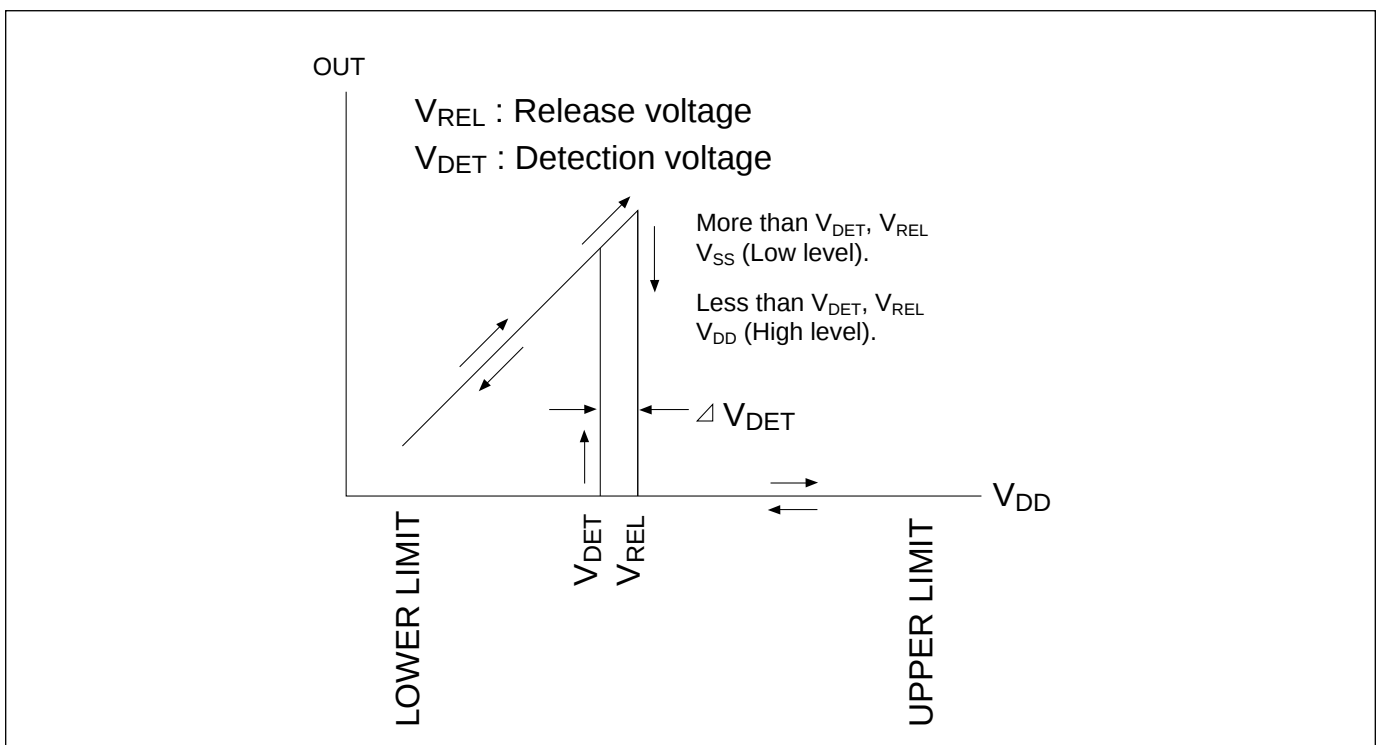
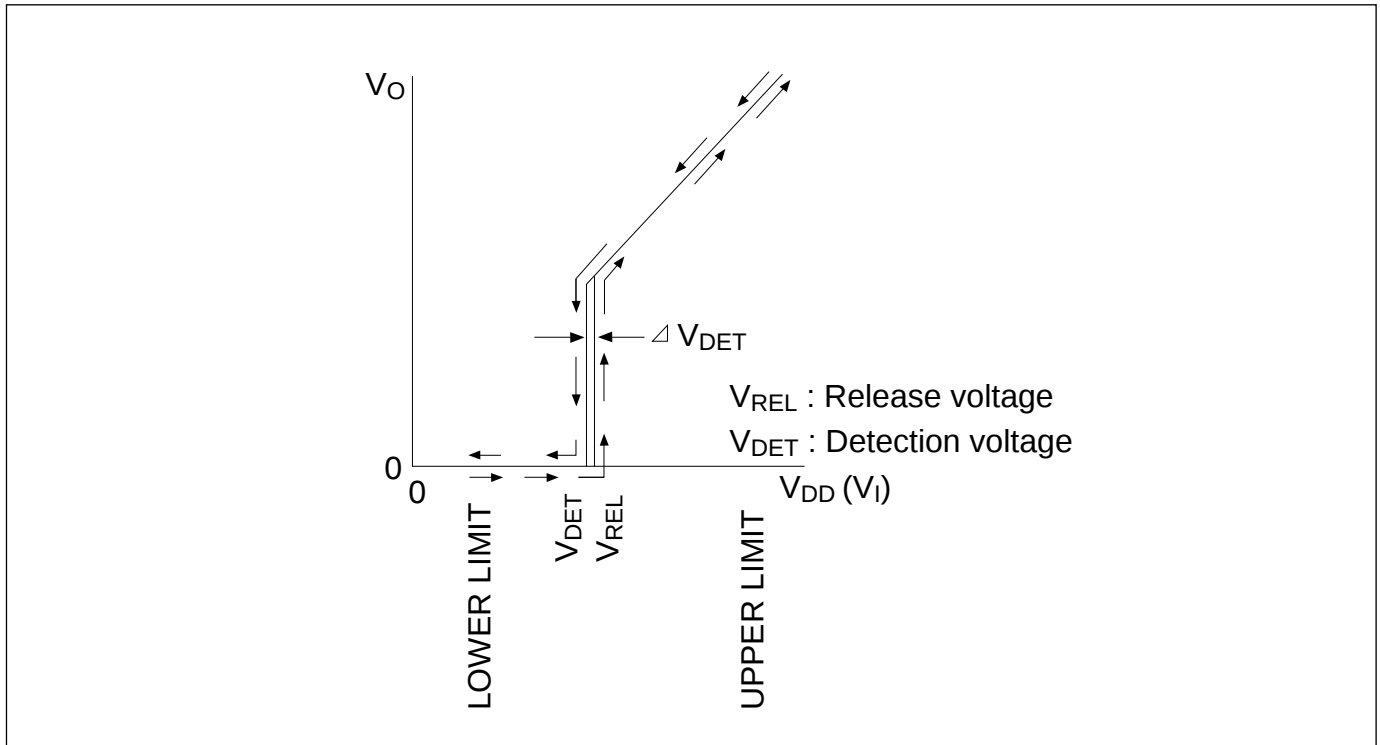
- * 1: Applicable to SCI7700YAS
 * 2: Applicable to SCI7700YFA
 * 3: Applicable to SCI7701YCB
 * 4: Applicable to SCI7701YFB

SCI7700/01Y Series

November 1996

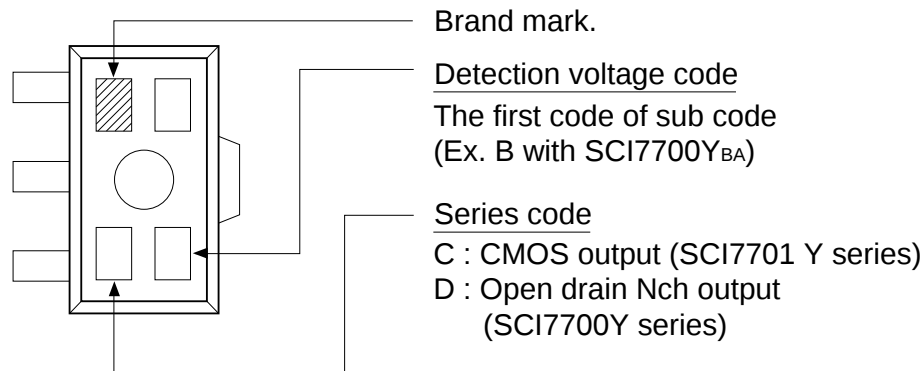
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■ PERFORMANCE CURVES



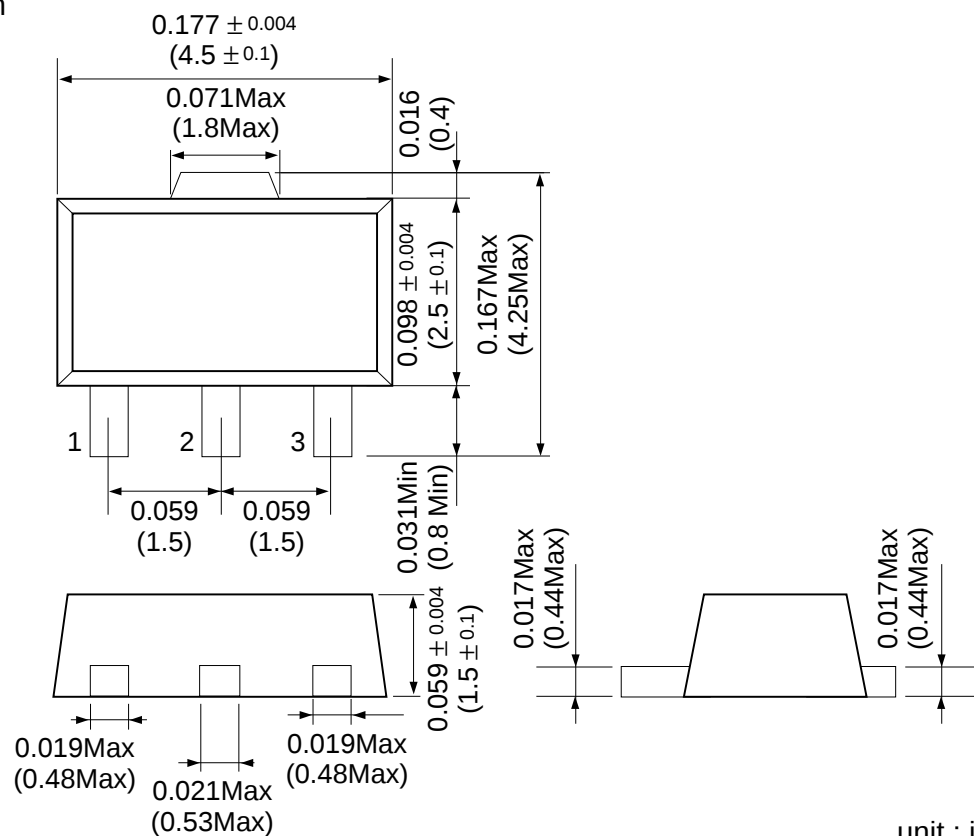
MARKING

An abbreviation is printed on SCI7700Yseries/SCI7701Yseries below, because its package size is very small.



PACKAGE DIMENSIONS

SOT 89-3 pin



unit : inch (mm)

SCI7700/01Y Series**November 1996****S-MOS**
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November 1996

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Printed in U.S.A.

389-1.0



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